- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates With 3-V to 5.5-V V<sub>CC</sub> Supply
- Operates up to 250 kbit/s
- One Driver and One Receiver
- Low Standby Current . . . 1 μA Typical
- External Capacitors . . . 4  $\times$  0.1  $\mu$ F
- Accepts 5-V Logic Input With 3.3-V Supply
- Designed to Be Interchangeable With Maxim MAX3221
- RS-232 Bus-Pin ESD Protection Exceeds ±15 kV Using Human-Body Model (HBM)
- Auto-Powerdown Feature Automatically Disables Drivers for Power Savings
- Applications
  - Battery-Powered, Hand-Held, and Portable Equipment
  - PDAs and Palmtop PCs
  - Notebooks, Subnotebooks, and Laptops
  - Digital Cameras
  - Mobile Phones and Wireless Devices

## description/ordering information

The MAX3221 consists of one line driver, one line receiver, and a dual charge-pump circuit with  $\pm$ 15-kV ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. These devices operate at data signaling rates up to 250 kbit/s and a maximum of 30-V/µs driver output slew rate.

т <sub>А</sub>	PACKAGE	<u>e</u> †	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–0°C to 70°C	SSOP (DB)	Tape and reel	MAX3221CDBR	MA3221C
	TSSOP (PW)	Tape and reel	MAX3221CPWR	MA3221C
-40°C to 85°C	SSOP (DB)	Tape and reel	MAX3221IDBR	MB3221I
-40 C 10 85 C	TSSOP (PW)	Tape and reel	MAX3221IPWR	MB3221I

### **ORDERING INFORMATION**

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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	DB OR PW PACKAGE (TOP VIEW)							
V+ [ C1- [ C2+ [ C2- [ V- [	1 2 3 4 5 6 7 8	16 15 14 13 12 11 10 9	FORCEOFF   V <sub>CC</sub>   GND   DOUT   FORCEON   DIN   INVALID   ROUT					

## description/ordering information (continued)

Flexible control options for power management are available when the serial port is inactive. The auto-powerdown feature functions when FORCEON is low and FORCEOFF is high. During this mode of operation, if the device does not sense a valid RS-232 signal on the receiver input, the driver output is disabled. If FORCEOFF is set low and EN is high, both the driver and receiver are shut off, and the supply current is reduced to 1  $\mu$ A. Disconnecting the serial port or turning off the peripheral drivers causes the auto-powerdown condition to occur. Auto-powerdown can be disabled when FORCEON and FORCEOFF are high. With auto-powerdown enabled, the device is activated automatically when a valid signal is applied to the receiver input. The INVALID output notifies the user if an RS-232 signal is present at the receiver input. INVALID is high (valid data) if the receiver input voltage is greater than 2.7 V or less than -2.7 V, or has been between -0.3 V and 0.3 V for less than 30  $\mu$ s. Refer to Figure 5 for receiver input levels.

# Function Tables

		INPUTS		OUTPUT	
DIN	FORCEON	FORCEOFF	VALID RIN RS-232 LEVEL	DOUT	DRIVER STATUS
Х	Х	L	Х	Z	Powered off
L	Н	н	Х	Н	Normal operation with
н	Н	н	Х	L	auto-powerdown disabled
L	L	н	Yes	Н	Normal operation with
н	L	н	Yes	L	auto-powerdown enabled
L	L	н	No	Z	Powered off by
н	L	Н	No	Z	auto-powerdown feature

H = high level, L = low level, X = irrelevant, Z = high impedance

EACH RECEIVER

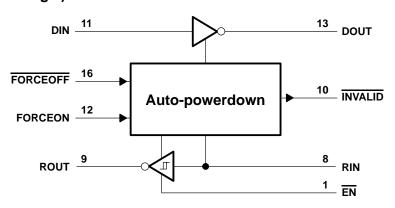
	INF	PUTS	OUTPUT
RIN	EN	VALID RIN RS-232 LEVEL	ROUT
L	L	Х	Н
н	L	х	L
х	Н	х	Z
Open	L	No	Н

H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = disconnected input or connected driver off



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logic diagram (positive logic)



## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, V <sub>CC</sub> (see Note 1)	–0.3 V to 6 V
Positive output supply voltage range, V+ (see Note 1)	$\dots \dots \dots -0.3$ V to 7 V
Negative output supply voltage range, V– (see Note 1)	$\ldots$ 0.3 V to –7 V
Supply voltage difference, V+ – V– (see Note 1)	13 V
Input voltage range, VI: Driver (FORCEOFF, FORCEON, EN)	–0.3 V to 6 V
Receiver	–25 V to 25 V
Output voltage range, V <sub>O</sub> : Driver	13.2 V to 13.2 V
Receiver (INVALID)	–0.3 V to V <sub>CC</sub> + 0.3 V
Package thermal impedance, $\theta_{JA}$ (see Note 2): DB package	
PW package	108°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T <sub>stg</sub>	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The package thermal impedance is calculated in accordance with JESD 51-7.

### recommended operating conditions (see Note 3 and Figure 6)

				MIN	NOM	MAX	UNIT
	Supply voltage		V <sub>CC</sub> = 3.3 V	3	3.3	3.6	V
				4.5	5	5.5	v
V	VIH Driver and control high-level input voltage		$V_{CC} = 3.3 V$	2			V
VIH	Driver and control high-level input voltage	DIN, FORCEOFF, FORCEON, EN	$V_{CC} = 5 V$	2.4			v
$V_{IL}$	Driver and control low-level input voltage	DIN, FORCEOFF, FORCEON, EN				0.8	V
VI	Driver and control input voltage	DIN, FORCEOFF, FORCEON		0		5.5	V
VI	VI Receiver input voltage			-25		25	V
т.	Operating free-air temperature			0		70	°C
TA			MAX32211	-40		85	C

NOTE 3: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.



NOTES: 1. All voltages are with respect to network GND.

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## electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Figure 6)

	PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Ц	Input leakage current	FORCEOFF, FORCEON, EN			±0.01	±1	μΑ
lcc	Auto-powerdown disabled F   Supply current Powered off N	Auto-powerdown disabled	No load, FORCEOFF and FORCEON at $V_{CC}$		0.3	1	mA
		No load, FORCEOFF at GND		1	10		
	(T <sub>A</sub> = 25°C)	Auto-powerdown enabled	No load, <del>FORCEOFF</del> at V <sub>CC</sub> , FORCEON at GND, All RIN are open or grounded		1	10	μA

<sup>†</sup> All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

NOTE 3: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.

## **DRIVER SECTION**

## electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Figure 6)

	PARAMETER	TEST C	ONDITIONS	MIN	TYP†	MAX	UNIT
VOH	High-level output voltage	DOUT at $R_L = 3 k\Omega$ to GND,	DIN = GND	5	5.4		V
VOL	Low-level output voltage	DOUT at $R_L = 3 k\Omega$ to GND,	$DIN = V_{CC}$	-5	-5.4		V
ЧH	High-level input current	$V_I = V_{CC}$			±0.01	±1	μA
١ <sub>IL</sub>	Low-level input current	V <sub>I</sub> at GND			±0.01	±1	μA
100		V <sub>CC</sub> = 3.6 V,	$V_{O} = 0 V$		±35	±60	m۸
los	Short-circuit output current <sup>‡</sup>	V <sub>CC</sub> = 5.5 V,	$V_{O} = 0 V$		±35	±60	mA
r <sub>o</sub>	Output resistance	$V_{CC}$ , V+, and V– = 0 V,	$V_{O} = \pm 2 V$	300	10M		Ω
loff	Output leakage current	FORCEOFF = GND,	$V_{O} = \pm 12 \text{ V},  V_{CC} = 0 \text{ to } 5.5 \text{ V}$			±25	μΑ

<sup>†</sup> All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

<sup>‡</sup> Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.

NOTE 3: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.

### switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Figure 6)

	PARAMETER	TES	TEST CONDITIONS			түр†	MAX	UNIT
	Maximum data rate	C <sub>L</sub> = 1000 pF,	$R_L = 3 k\Omega$ ,	See Figure 1	150	250		kbit/s
<sup>t</sup> sk(p)	Pulse skew <sup>§</sup>	C <sub>L</sub> = 150 pF to 2500 pF,	$R_L = 3 k\Omega$ to 7 k $\Omega$ ,	See Figure 2		100		ns
SR(tr)	Slew rate, transition region	Slew rate, transition region $V_{CC} = 3.3 V$ ,	C <sub>L</sub> = 150 pF to 1000 pF		6		30	V/µs
	(see Figure 1)	$R_L = 3 k\Omega$ to 7 k $\Omega$	C <sub>L</sub> = 150 pF to 2500 pF		4		30	v/µs

<sup>†</sup> All typical values are at  $V_{CC}$  = 3.3 V or  $V_{CC}$  = 5 V, and  $T_A$  = 25°C.

\$ Pulse skew is defined as  $|t_{PLH} - t_{PHL}|$  of each channel of the same device. NOTE 3: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V.

## ESD protection

TERM	INAL	TEST CONDITIONS	тур	UNIT
NAME	NO. TEST CONDITIONS		116	UNIT
DOUT	13	НВМ	±15	kV



## **RECEIVER SECTION**

## electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Figure 6)

	PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
VOH	High-level output voltage	I <sub>OH</sub> = -1 mA	V <sub>CC</sub> -0.6 V	V <sub>CC</sub> –0.1 V		V
VOL	Low-level output voltage	I <sub>OL</sub> = 1.6 mA			0.4	V
V/	Positive-going input threshold voltage	V <sub>CC</sub> = 3.3 V	C = 3.3 V 1	1.6	2.4	V
VIT+	Positive-going input timeshold voltage	$V_{CC} = 5 V$		1.9	2.4	v
V	Negative-going input threshold voltage	V <sub>CC</sub> = 3.3 V	0.6	1.1		V
VIT-	Negative-going input threshold voltage	$V_{CC} = 5 V$	0.8	1.4	0.4 .6 2.4 .9 2.4 .1 .4 .5	v
V <sub>hys</sub>	Input hysteresis (V <sub>IT+</sub> – V <sub>IT</sub> _)			0.5		V
loff	Output leakage current	FORCEOFF = 0 V		±0.05	±10	μA
ri	Input resistance	$V_{I} = \pm 3 V \text{ to } \pm 25 V$	3	5	7	kΩ

<sup>†</sup> All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C. NOTE 3: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.

### switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3)

	PARAMETER	TEST CONDITIONS	ΜΙΝ ΤΥΡ <sup>†</sup> ΜΑΧ	UNIT
<sup>t</sup> PLH	Propagation delay time, low- to high-level output	C <sub>L</sub> = 150 pF, See Figure 3	150	ns
<sup>t</sup> PHL	Propagation delay time, high- to low-level output	C <sub>L</sub> = 150 pF, See Figure 3	150	ns
ten	Output enable time	$C_L$ = 150 pF, $R_L$ = 3 k $\Omega$ , See Figure 4	200	ns
t <sub>dis</sub>	Output disable time	$C_L$ = 150 pF, $R_L$ = 3 k $\Omega$ , See Figure 4	200	ns
<sup>t</sup> sk(p)	Pulse skew <sup>‡</sup>	See Figure 3	50	ns

<sup>†</sup> All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

<sup>‡</sup> Pulse skew is defined as  $|t_{PLH} - t_{PHL}|$  of each channel of the same device. NOTE 3: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.

## **ESD** protection

TERMINAL		TEST CONDITIONS	тур	UNIT
NAME	NO.	TEST CONDITIONS		
RIN	8	НВМ	±15	kV



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## AUTO-POWERDOWN SECTION

# electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

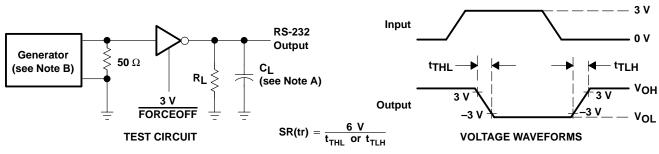
PARAMETER		TEST CONDITIONS	MIN	MAX	UNIT
V <sub>T+(valid)</sub>	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND, $\overline{\text{FORCEOFF}} = V_{CC}$		2.7	V
V <sub>T-(valid)</sub>	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND, FORCEOFF = $V_{CC}$	-2.7		V
VT(invalid)	Receiver input threshold for INVALID low-level output voltage	FORCEON = GND, FORCEOFF = $V_{CC}$	-0.3	0.3	V
VOH	INVALID high-level output voltage	$I_{OH} = -1 \text{ mA}$ , FORCEON = GND, FORCEOFF = V <sub>CC</sub>	V <sub>CC</sub> -0.6		V
VOL	INVALID low-level output voltage	$I_{OL} = 1.6 \text{ mA}$ , FORCEON = GND, FORCEOFF = V <sub>CC</sub>		0.4	V

# switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

PARAMETER		MIN TYP <sup>†</sup>	MAX	UNIT
<sup>t</sup> valid	Propagation delay time, low- to high-level output	1		μs
<sup>t</sup> invalid	Propagation delay time, high- to low-level output	30		μs
t <sub>en</sub>	Supply enable time	100		μs

<sup>†</sup> All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

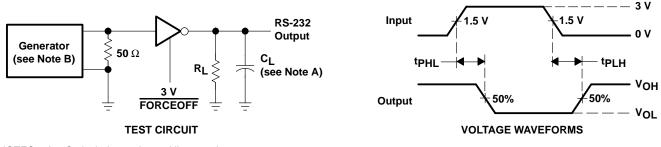




## PARAMETER MEASUREMENT INFORMATION

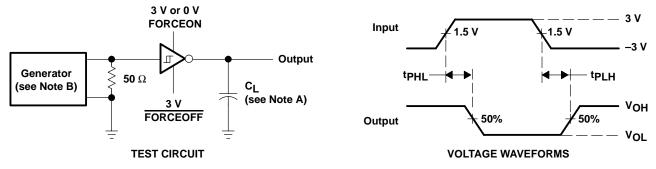
NOTES: A. C<sub>L</sub> includes probe and jig capacitance. B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_{\Omega}$  = 50  $\Omega$ , 50% duty cycle,  $t_r \le 10$  ns,  $t_f \le 10$  ns.

### Figure 1. Driver Slew Rate



NOTES: A. CL includes probe and jig capacitance. B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_0 = 50 \Omega$ , 50% duty cycle,  $t_f \le 10$  ns.  $t_f \le 10$  ns.

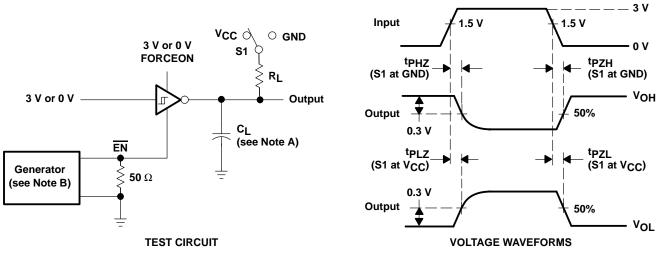
Figure 2. Driver Pulse Skew



NOTES: A. CL includes probe and jig capacitance. B. The pulse generator has the following characteristics:  $Z_O = 50 \Omega$ , 50% duty cycle,  $t_f \le 10$  ns,  $t_f \le 10$  ns.

## Figure 3. Receiver Propagation Delay Times



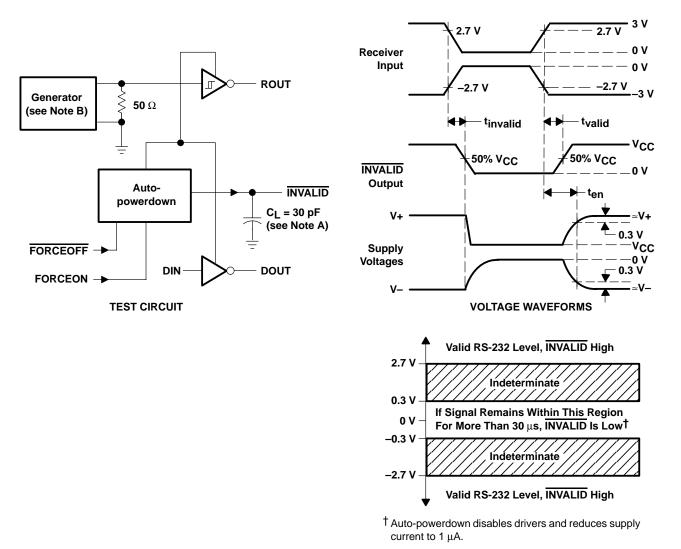


## PARAMETER MEASUREMENT INFORMATION

- NOTES: A.  $C_{\mbox{L}}$  includes probe and jig capacitance.
  - B. The pulse generator has the following characteristics:  $Z_0 = 50 \Omega$ , 50% duty cycle,  $t_r \le 10$  ns,  $t_f \le 10$  ns.
    - C.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
    - D.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .

#### Figure 4. Receiver Enable and Disable Times





## PARAMETER MEASUREMENT INFORMATION

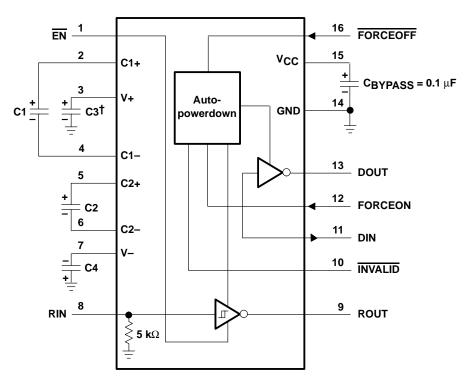
NOTES: A. CL includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 5 kbit/s,  $Z_0 = 50 \Omega$ , 50% duty cycle,  $t_f \le 10$  ns.  $t_f \le 10$  ns.

## Figure 5. INVALID Propagation Delay Times and Driver Enabling Time



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## **APPLICATION INFORMATION**

 $^{\dagger}$  C3 can be connected to V\_CC or GND. NOTE A: Resistor values shown are nominal.

VLC VS OAI AOITOR VALUED					
vcc	C1	C2, C3, and C4			
$\begin{array}{c} \textbf{3.3 V} \pm \textbf{0.3 V} \\ \textbf{5 V} \pm \textbf{0.5 V} \\ \textbf{3 V to 5.5 V} \end{array}$	0.1 μF 0.047 μF 0.1 μF	0.1 μF 0.33 μF 0.47 μF			

#### V<sub>CC</sub> vs CAPACITOR VALUES

## Figure 6. Typical Operating Circuit and Capacitor Values



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